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Kind regards,

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74LVT14

3.3 V hex inverter Schmitt trigger

Rev. 02 — 25 April 2008   **Product data sheet**

1. General description

The 74LVT14 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V. It is capable of transforming slowly changing input signals into sharply defined, jitter free output signals. In addition, it has a greater noise margin than conventional inverters.

Each circuit contains a Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem-pole output. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive-going and negative-going inputs. The threshold differential (typically 600 mV) is determined internally by resistor ratios and is insensitive to temperature and supply voltage variations.
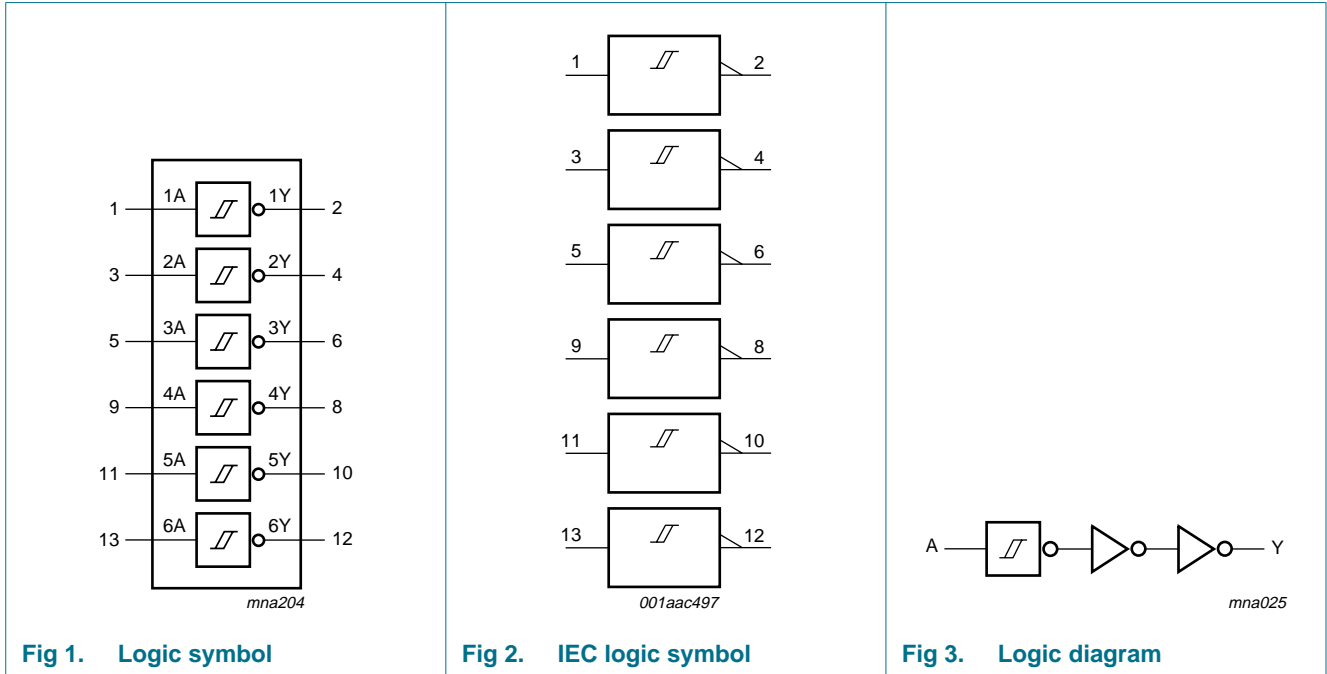
2. Features

■ Different positive and negative going input threshold voltages
■ Tolerant of slow input transitions
■ High noise immunity
■ TTL input and output switching levels
■ Output capability: +32 mA/−20 mA
■ Latch-up protection exceeds 500 mA per JESD78 class II level A
■ ESD protection:
   ◆ HBM JESD22-A114E exceeds 2000 V
   ◆ MM JESD22-A115-A exceeds 200 V

3. Ordering information

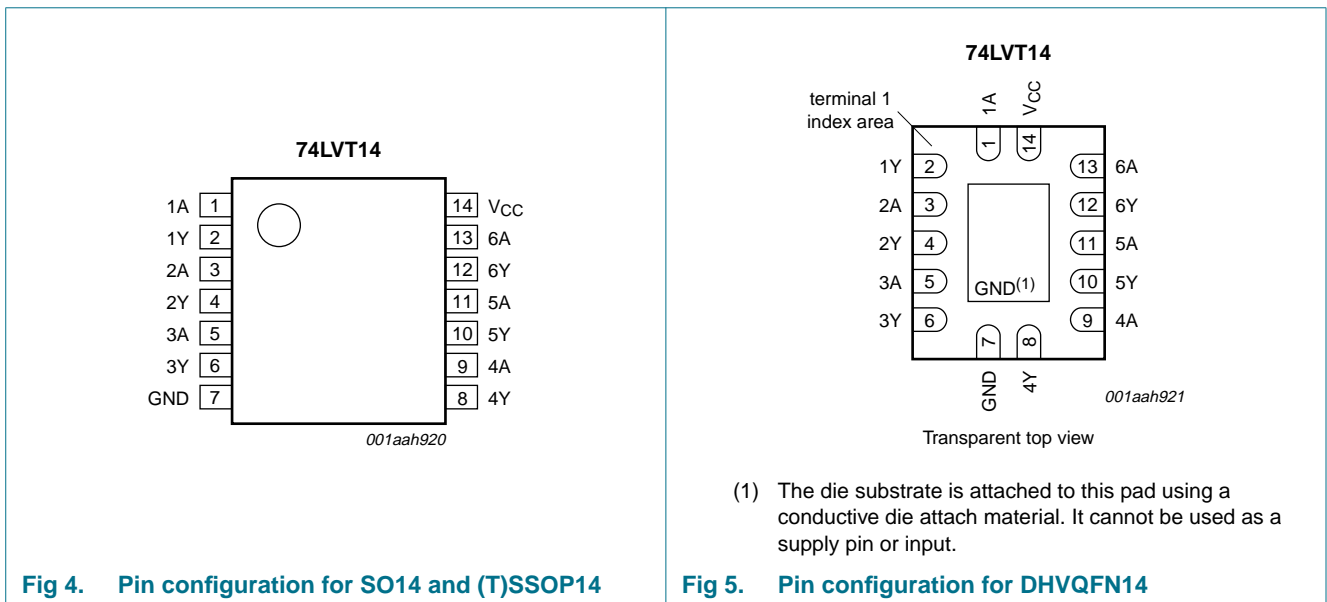**Table 1.   Ordering information**

Type number	Package			
	Temperature range	**Name**	**Description**	**Version**
74LVT14D	−40 °C to +85 °C	SO14	plastic small outline package; 14 leads; body width 7.5 mm	SOT108-1
74LVT14DB	−40 °C to +85 °C	SSOP14	plastic shrink small outline package; 14 leads; body width 5.3 mm	SOT337-1
74LVT14PW	−40 °C to +85 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1
74LVT14BQ	−40 °C to +85 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body $2.5 \times 4.5 \times 0.85$ mm	SOT762-1

NXP founded by Philips

4. Functional diagram

Fig 1.   Logic symbol

Fig 2.   IEC logic symbol

Fig 3.   Logic diagram

5. Pinning information

5.1 Pinning

Fig 4.   Pin configuration for SO14 and (T)SSOP14

(1) The die substrate is attached to this pad using a conductive die attach material. It cannot be used as a supply pin or input.

Fig 5.   Pin configuration for DHVQFN14

5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A to 6A	1, 3, 5, 9, 11, 13	data input
1Y to 6Y	2, 4, 6, 8, 10, 12	data output
GND	7	ground (0 V)
V_{CC}	14	positive supply voltage

6. Functional description

Table 3. Function selection

Inputs	Output
nA	**nY**
L	H
H	L

[1] H = HIGH voltage level;
    L = LOW voltage level.

7. Limiting values

Table 4. Limiting values [1]
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage			−0.5	+4.6	V
V_I	input voltage		[2]	−0.5	+7.0	V
V_O	output voltage	output in OFF or HIGH state	[2]	−0.5	+7.0	V
I_{IK}	input clamping current	$V_I < 0$ V		−50	-	mA
I_{OK}	output clamping current	$V_O < 0$ V		−50	-	mA
I_O	output current	output in LOW state		-	64	mA
		output in HIGH state		−32	-	mA
T_{stg}	storage temperature			−65	+150	°C
T_j	junction temperature				+150	°C
P_{tot}	total power dissipation	$T_{amb} = −40$ °C to +85 °C	[3]		500	mW

[1] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

[2] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[3] For SO14 packages: above 70 °C derate linearly with 8 mW/K.
    For SSOP14 and TSSOP14 packages: above 60 °C derate linearly with 5.5 mW/K.
    For DHVQFN14 packages: above 60 °C derate linearly with 4.5 mW/K.

8. Recommended operating conditions

Table 5.   Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		2.7	-	3.6	V
V_I	input voltage		0	-	5.5	V
I_{OH}	HIGH-level output current		−20	-	-	mA
I_{OL}	LOW-level output current		-	-	32	mA
T_{amb}	ambient temperature	in free air	−40	-	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	output enabled	0	-	10	ns/V

9. Static characteristics

Table 6.   Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	−40 °C to +85 °C			Unit
			Min	Typ[1]	Max	
V_{T+}	positive-going threshold voltage	V_{CC} = 3.3 V; see Figure 7	1.5	1.7	2.0	V
V_{T-}	negative-going threshold voltage	V_{CC} = 3.3 V; see Figure 7	0.9	1.1	1.3	V
V_H	hysteresis voltage	V_{CC} = 3.3 V; see Figure 7	0.4	0.6	-	V
V_{IK}	input clamping voltage	V_{CC} = 2.7 V; I_{IK} = −18 mA	−1.2	-	-	V
V_{IH}	HIGH-level input voltage		2.0	-	-	V
V_{IL}	LOW-level input voltage		-	-	0.8	
V_{OH}	HIGH-level output voltage	V_{CC} = 2.7 V to 3.6 V; I_{OH} = −100 µA	V_{CC} − 0.2	-	-	V
		V_{CC} = 2.7 V; I_{OH} = −6 mA	2.4	-	-	V
		V_{CC} = 3.0 V; I_{OH} = −20 mA	2.0	-	-	V
V_{OL}	LOW-level output voltage	V_{CC} = 2.7 V; I_{OL} = 100 µA	-	-	0.2	V
		V_{CC} = 2.7 V; I_{OL} = 24 mA	-	-	0.5	V
		V_{CC} = 3.0 V; I_{OL} = 32 mA	-	-	0.5	V
I_I	input leakage current	V_{CC} = 0 V or 3.6 V; V_I = 5.5 V	-	-	10	µA
		V_{CC} = 3.6 V; V_I = V_{CC} or GND	-	-	±1	µA
I_{OFF}	power-off leakage current	V_{CC} = 0 V; V_I or V_O = 0 V to 4.5 V	-	-	±100	µA
I_{CC}	supply current	V_{CC} = 3.6 V; V_I = GND or V_{CC}; I_O = 0 A				
		outputs HIGH	-	-	0.02	mA
		outputs LOW	-	1.5	3	mA
ΔI_{CC}	additional supply current	per input pin; V_{CC} = 3.0 V to 3.6 V; one input = V_{CC} − 0.6 V other inputs at V_{CC} or GND [2]	-	-	0.2	mA
C_I	input capacitance	V_I = 0 V or 3.0 V	-	3	-	pF

[1]   All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

[2]   This is the increase in the supply current for each input at the specified voltage level other than V_{CC} or GND.

10. Dynamic characteristics

Table 7.   Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 8.

Symbol	Parameter	Conditions	−40 °C to +85 °C			Unit
			Min	Typ[1]	Max	
t_{PLH}	LOW to HIGH propagation delay	nA to nY				
		V_{CC} = 2.7 V	-	-	6.9	ns
		V_{CC} = 3.3 V + 0.3 V	1.0	3.8	5.7	ns
t_{PHL}	HIGH to LOW propagation delay	nA to nY				
		V_{CC} = 2.7 V	-	-	4.1	ns
		V_{CC} = 3.3 V + 0.3 V	1.0	3.2	4.5	ns

[1]   Typical values are measured at T_{amb} = 25 °C and V_{CC} = 3.3 V.
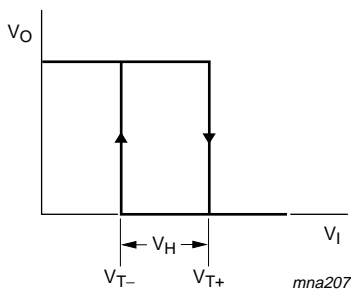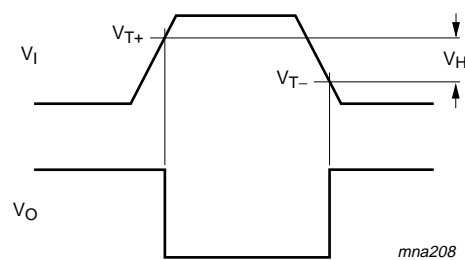
11. Waveforms
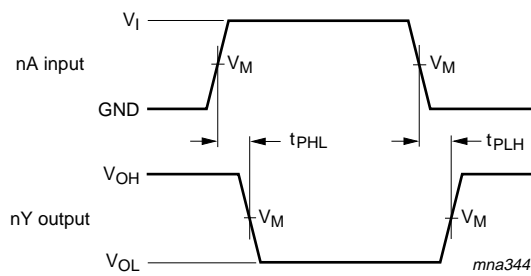
See Table 8 for measurement points.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 6.   nA Input to nY output propagation delays
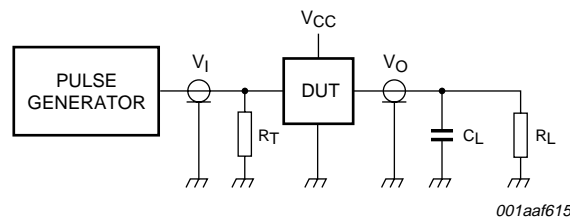

a.   Transfer characteristics

b.   Voltage levels

Fig 7.   Definition of V_{T+}, $V_{T−}$ and V_H

Table 8.　Measurement points

V_{CC}	Input	Output
	V_M	V_M
2.7 V to 3.6 V	1.5 V	1.5 V
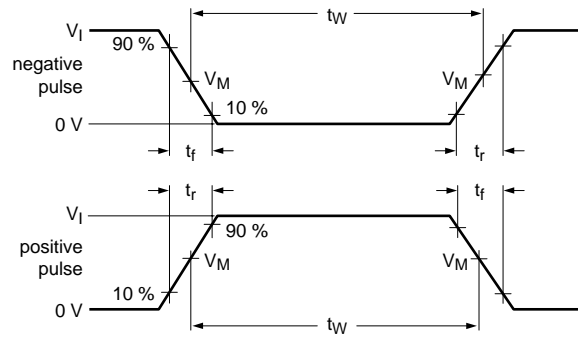
Test data is given in given in Table 9.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig 8.　Load circuitry for switching times

Table 9.　Test data

Supply	Input pulse requirements				Load	
V_{CC}	V_I	Repetition rate	t_W	t_r, t_f	R_L	C_L
2.7 V to 3.3 V	2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns	500 Ω	50 pF

12. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm **SOT108-1**

DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A₁	A₂	A₃	b_p	c	D(1)	E(1)	e	H_E	L	L_p	Q	v	w	y	Z(1)	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT108-1	076E06	MS-012				~~99-12-27~~ 03-02-19

Fig 9.   Package outline SOT108-1 (SO14)

74LVT14_2

3.3 V hex inverter Schmitt trigger

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A₁	A₂	A₃	b_p	c	D[1]	E[1]	e	H_E	L	L_p	Q	v	w	y	Z[1]	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT337-1		MO-150				~~99-12-27~~ 03-02-19
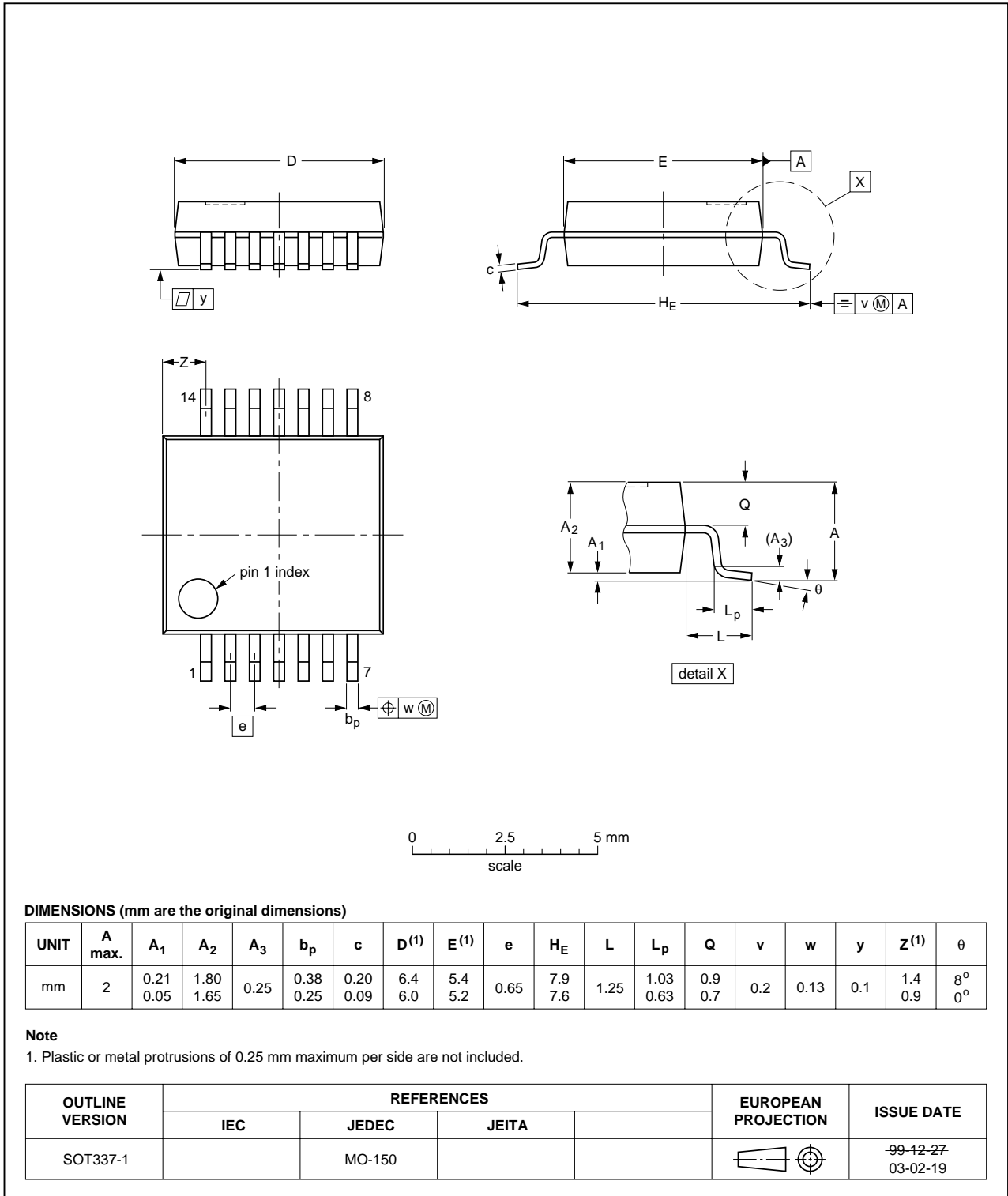
Fig 10. Package outline SOT337-1 (SSOP14)

74LVT14_2

Product data sheet

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm   **SOT402-1**

DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A₁	A₂	A₃	bₚ	c	D (1)	E (2)	e	H_E	L	Lₚ	Q	v	w	y	Z (1)	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT402-1		MO-153				~~99-12-27~~ 03-02-18

Fig 11. Package outline SOT402-1 (TSSOP14)

74LVT14_2

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm
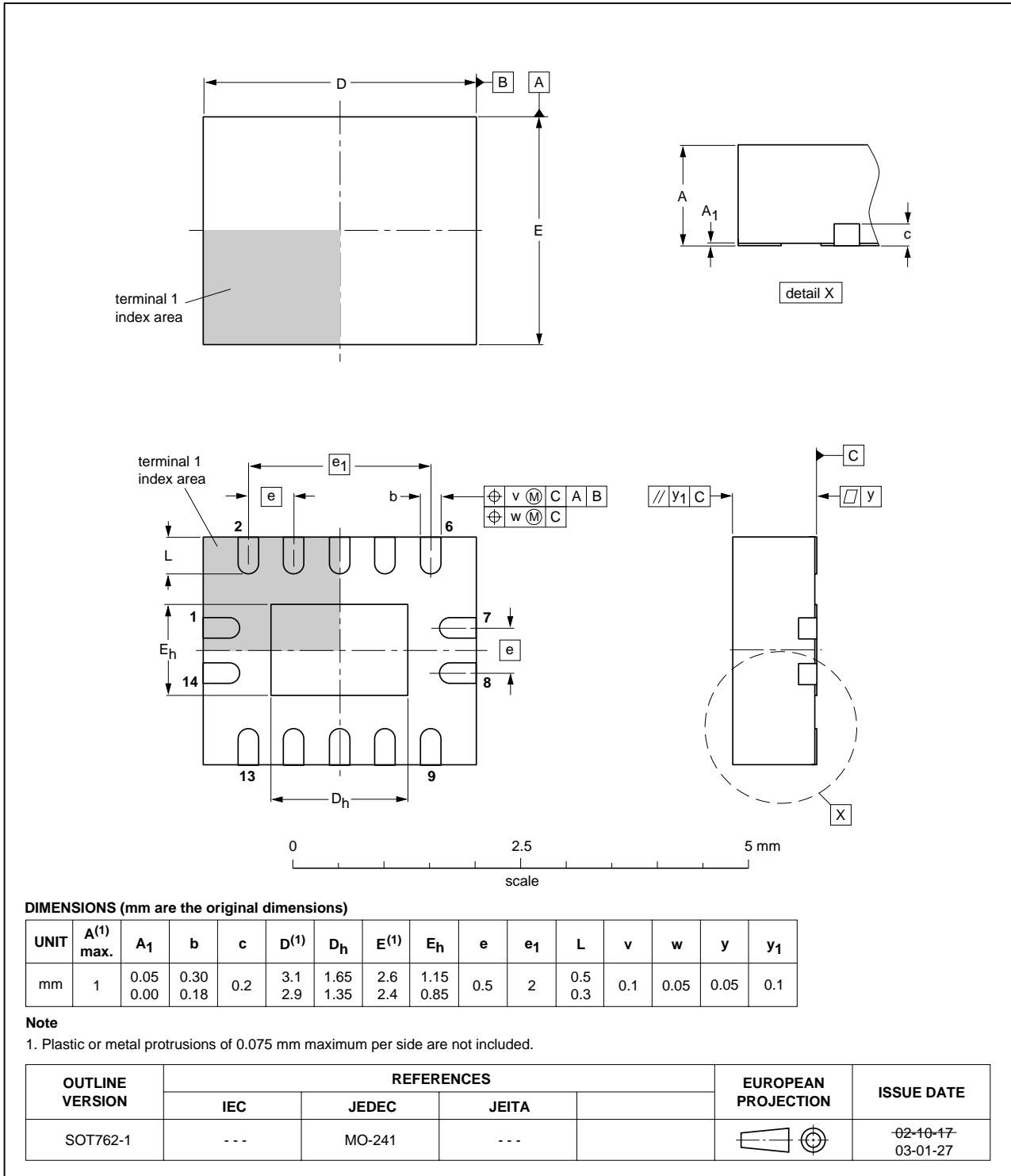
SOT762-1

DIMENSIONS (mm are the original dimensions)

UNIT	A[1] max.	A₁	b	c	D[1]	D_h	E[1]	E_h	e	e₁	L	v	w	y	y₁
mm	1	0.05 / 0.00	0.30 / 0.18	0.2	3.1 / 2.9	1.65 / 1.35	2.6 / 2.4	1.15 / 0.85	0.5	2	0.5 / 0.3	0.1	0.05	0.05	0.1

Note

1. Plastic or metal protrusions of 0.075 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT762-1	- - -	MO-241	- - -			~~02-10-17~~ 03-01-27

Fig 12. Package outline SOT762-1 (DHVQFN14)

13. Abbreviations

Table 10.   Abbreviations

Acronym	Description
BiCMOS	Integrated Bipolar junction transistors and CMOS
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11.   Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVT14_2	20080425	Product data sheet	-	74LVT14_1
Modifications:	- The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. - Legal texts have been adapted to the new company name where appropriate. - Quick reference section removed. - DHVQFN14 package added to Section 3 "Ordering information" and Section 12 "Package outline". - Section 13 "Abbreviations" added.				
74LVT14_1	19960828	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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